# 76V Precision, High-Voltage, Current-Sense Amplifier

#### **General Description**

The MAX40010 single-channel high-side precision current-sense amplifier with an input common-mode voltage range from 2.7V to 76V, making it ideal for communications, automotive, data centers and other systems where high-voltage current monitoring is critical. The MAX40010 offer accuracy specifications of less than  $12\mu$ V (max) Input Offset voltage and less than 0.1% (max) gain error. By offering precision offset and gain error specifications, the MAX40010 makes it possible to sense very small sense/shunt resistors, further improving system efficiencies and power dissipation through the sense element.

The MAX40010 features 80kHz of small signal bandwidth and four unique gain options (12.5V/V, 20V/V, 50V/V, and 100V/V). The device's current sense inputs have EMIR filters to reject RF found in communications equipment.

The MAX40010 operates over the -40° C to +  $125^{\circ}$ C temperature range and is offered in a 6-bump, 1mm x 1.5mm wafer-lever package (WLP) with 0.5mm pitch and a SOT23 U6SN+1 package.

#### **Benefits and Features**

- Input Common Mode +2.7V to +76V
- Ultra-Tiny 1mm x 1.5mm 6-bump WLP and SOT23 Packages
- Low 12µV (max) Input Offset Voltage
- Low 0.1%(max) Gain Error
- Available Gain Options:
  - G = 12.5V/V: MAX40010L
  - G = 20V/V: MAX40010T
  - G = 50V/V: MAX40010F
  - G = 100V/V: MAX40010H

#### **Applications**

- Base-Stations and Communication Equipment
- Server Backplanes/Data Centers
- Automotive Sensing
- Energy Management
- Solar Panel Monitoring

Ordering Information appears at end of data sheet.





# **Typical Operating Circuit**

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### **Absolute Maximum Ratings**

| V <sub>DD</sub> to GND                    | 0.3V to +6.0V |
|---|---------------|
| RS+, RS- to GND                           | 0.3V to +80V  |
| RS+ to RS- (Continuous)                   | ±24V          |
| Continuous (> 1s) Input Current (Any Pin) | ±10mA         |

### Package Thermal Characteristics (Note 1)

#### 6-Bump WLP

| Continuous Power Dissipation                           |           |
|--|-----------|
| (Derate mW/°C above +70°C)                             | 12.34mW   |
| Junction-to-Ambient Thermal Resistance $(\theta_{JA})$ | 81.03°C/W |

| Operating Temperature Range                 | -40°C to +125°C |
|---|-----------------|
| Junction Temperature                        | +150°C          |
| Storage Temperature Range                   | -65°C to +150°C |
| Reflow Soldering Peak Temperature (Pb-free) | +260°C          |

#### 6-Pin SOT23

| Continuous Power Dissipation                           |           |
|--|-----------|
| (Derate mW/°C above +70°C)                             | 13.40mW   |
| Junction-to-Ambient Thermal Resistance $(\theta_{JA})$ | 74.60°C/W |
| Junction-to-Case Thermal Resistance $(\theta_{JC})$    | 6.0°C/W   |

Note 1: Package thermal resistances were obtained using the method described in JEDEC specification JESD51-7, using a four-layer board. For detailed information on package thermal considerations, refer to www.maximintegrated.com/thermal-tutorial.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

### **Electrical Characteristics**

 $(V_{RS+} = V_{RS-} = +36V, V_{DD} = +3.3V, V_{SENSE} = V_{RS+} - V_{RS-} = 1mV, T_A = -40^{\circ}C$  to +125°C unless otherwise noted. Typical values are at T<sub>A</sub> =+25°C). (Note 2)

| PARAMETER                                       | SYMBOL                              | CONDITIONS                                   | MIN | TYP | MAX | UNITS |
|---|-------------------------------------|--|-----|-----|-----|-------|
| DC CHARACTERISTICS                              |                                     |  | ·   |     |     |       |
| Supply Voltage                                  | V <sub>DD</sub>                     | Guaranteed by PSRR                           | 2.7 |     | 5.5 | V     |
| Cumply Current                                  |                                     | T <sub>A</sub> = +25°C                       |     | 350 |     | μA    |
| Supply Current                                  | IDD                                 | -40°C < T <sub>A</sub> < +125°C              |     |     | 800 |       |
| Power-Supply Rejection Ratio                    | PSRR                                | $2.7V \le V_{DD} \le 5.5V$                   | 110 | 120 |     | dB    |
| Input Common-Mode Voltage<br>Range              | V <sub>CM</sub>                     | Guaranteed by CMRR                           | 2.7 |     | 76  | V     |
| Input Bias Current at $V_{RS^+}$ and $V_{RS^-}$ | I <sub>RS+</sub> , I <sub>RS-</sub> |  |     |     | 65  | μA    |
| Input Offset Current                            | I <sub>RS+</sub> - I <sub>RS-</sub> |  |     |     | 400 | nA    |
| Input Leakage Current                           | I <sub>RS+</sub> , I <sub>RS-</sub> | V <sub>DD</sub> = 0V, V <sub>RS+</sub> = 76V |     |     | 5   | μA    |
| Common-Mode Rejection Ratio                     | CMRR                                | +4.5V < V <sub>RS+</sub> < +76V              | 125 | 140 |     | dB    |
|   |                                     | T <sub>A</sub> = +25°C                       |     |     | ±12 | μV    |
| Input Offset Voltage                            | V <sub>OS</sub>                     | $-40^{\circ}C \le T_A \le +85^{\circ}C$      |     |     | ±25 | ·     |
|   |                                     | $-40^{\circ}C \le T_{A} \le +125^{\circ}C$   |     |     | ±25 |       |
| Input Offset Voltage Drift                      | TCV <sub>OS</sub>                   |  |     |     | 130 | nV/°C |
|   |                                     | MAX40010L (G = 12.5V/V)                      |     | 200 |     |       |
| Innut Conco Valtago                             |                                     | MAX40010T (G = 20V/V)                        |     | 125 |     | mV    |
| Input Sense Voltage                             | V <sub>SENSE</sub>                  | MAX40010F (G = 50V/V)                        |     | 50  |     | IIIV  |
|   |                                     | MAX40010H (G=100V/V)                         |     | 25  |     |       |

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### **Electrical Characteristics (continued)**

 $(V_{RS+} = V_{RS-} = +36V, V_{DD} = +3.3V, V_{SENSE} = V_{RS+} - V_{RS-} = 1mV, T_A = -40^{\circ}C \text{ to } +125^{\circ}C \text{ unless otherwise noted}. Typical values are the transformed of the transformation of transformation of the transformation of t$ at T<sub>A</sub> =+25°C). (Note 2)

| PARAMETER                          | SYMBOL            | CONDITIONS  | MIN                        | TYP  | MAX | UNITS  |
|------------------------------------|-------------------|---|----------------------------|------|-----|--------|
| Gain (Note 3)                      |                   | Full-Scale V <sub>SENSE</sub> = 200mV, Int.<br>reference = 2.5V   |                            | 12.5 |     |        |
|                                    | G                 | Full-Scale V <sub>SENSE</sub> = 125mV, Int.<br>reference = 2.5V   |                            | 20   |     | V/V    |
|                                    | G                 | Full-Scale VS <sub>ENSE</sub> = 50mV, Int.<br>reference = 2.5V  |                            | 50   |     | V/V    |
|                                    |                   | Full-Scale V <sub>SENSE</sub> = 25mV, Int.<br>reference = 2.5V  |                            | 100  |     |        |
|                                    |                   | T <sub>A</sub> = +25°C  |                            |      | 0.1 |        |
| Gain Error                         | GE                | $-40^{\circ}C \le T_{A} \le +85^{\circ}C$   |                            |      | 0.5 | %      |
|                                    |                   | $-40^{\circ}C \le T_{A} \le +125^{\circ}C$  |                            |      | 0.7 |        |
| Output Resistance                  | R <sub>OUT</sub>  |   |                            | 0.1  |     | mΩ     |
| Output Low Voltage                 | V <sub>OL</sub>   | Sink 500µA  |                            |      | 15  | mV     |
| Output High Voltage                | V <sub>OH</sub>   | Source 500µA  | V <sub>DD</sub> -<br>0.016 |      |     | V      |
| AC CHARACTERISTICS                 | •                 |   |                            |      |     |        |
| Signal Bandwidth                   | BW -3dB           | Gain = 50V/V Configuration<br>V <sub>SENSE</sub> > 5mV  |                            | 80   |     | kHz    |
| AC Power Supply Rejection<br>Ratio | AC PSRR           | f = 200kHz  |                            | 40   |     | dB     |
| AC CMRR                            | AC CMRR           | f = 200kHz  |                            | 48   |     | dB     |
| Output Transient Recovery Time     |                   | $\Delta V_{OUT}$ = 2V <sub>P-P</sub> , 0.1% final V <sub>OUT</sub> settling<br>with 400 $\Omega$ and 1nF onto 6pF ADC input<br>sampling capacitor |                            | 2    |     | μs     |
| Capacitive load stability          | C                 | With $240\Omega$ isolation resistor   |                            | 20   |     | nF     |
| Capacitive IDau Stability          | C <sub>LOAD</sub> | Without any isolation resistor  |                            | 200  |     | pF     |
| Input Voltage Noise Density        | e <sub>n</sub>    | f = 1kHz  |                            | 65   |     | nV/√Hz |
| Total Harmonic Distortion          | THD               | f = 1kHz, V <sub>OUT</sub> = 1V <sub>P-P</sub>  |                            | 60   |     | dB     |
| Power-up time (Note 4)             |                   |   |                            | 200  |     | μs     |
| Saturation Recovery Time           |                   |   |                            | 10   |     | μs     |

**Note 2:** All Devices are 100% production tested at  $T_A = +25$ °C. All temperature limits are guaranteed by design. **Note 3:** Gain and offset voltage are calculated based on two point measurements:  $V_{SENSE1} = 20\%$  full scale and  $V_{SENSE2} = 80\%$ full scale

Note 4: Output is high-Z during power-up.

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### **Typical Operating Characteristics**

 $(V_{RS+} = V_{RS-} = +36V, V_{DD} = +3.3V, V_{SENSE} = V_{RS+} - V_{RS-} = 1mV, T_A = -40^{\circ}C$  to +125°C, unless otherwise noted. Typical values are at T<sub>A</sub> =+25°C)



















# 76V Precision, High-Voltage, Current-Sense Amplifier

### **Typical Operating Characteristics (continued)**

 $(V_{RS+} = V_{RS-} = +36V, V_{DD} = +3.3V, V_{SENSE} = V_{RS+} - V_{RS-} = 1mV, T_A = -40^{\circ}C$  to +125°C, unless otherwise noted. Typical values are at T<sub>A</sub> =+25°C)

















# 76V Precision, High-Voltage, Current-Sense Amplifier

## **Pin Configurations**



## **Pin Description**

| Р   | IN    | NAME | FUNCTION   |  |
|-----|-------|------|--|--|
| WLP | SOT23 |      | FUNCTION   |  |
| B1  | 5     | RS+  | External Resistor Power-Side Connection Input  |  |
| A1  | 6     | RS-  | External Resistor Load-Side Connection Input   |  |
| A3  | 4     | VDD  | Supply Voltage Input   |  |
| B2  | 2     | GND  | Ground or Supply Return Input  |  |
| B3  | 3     | OUT  | Output. Output is proportional to the magnitude of differential sense input voltage. |  |
| A2  | 1     | NC   | No Connect.  |  |

# 76V Precision, High-Voltage, Current-Sense Amplifier

## Functional (or Block) Diagram



Figure 1 : MAX40010 Functional Diagram

#### **Detailed Description**

The MAX40010 high-side, current-sense amplifiers feature a 2.7V to 76V input common-mode range that is independent of supply voltage. This feature allows the monitoring of current out of a battery as low as 2.7V and enables high-side current sensing at voltages greater than the supply voltage (VDD). The MAX40010 monitors current through an external current-sense resistor and amplifies the voltage across the resistor.

High-side current monitoring does not interfere with the ground path of the load being measured, making the MAX40010 particularly useful in a wide range of high-voltage systems.

The MAX40010 operates as follows: current from the source flows through R<sub>SENSE</sub> to the load (Figure 1), creating a sense voltage, V<sub>SENSE</sub>. The internal op amp A1 force the current through an internal gain resistor RG1 at RS+ input, such that its voltage drop equals the voltage drop (V<sub>SENSE</sub>) across the external sense resistors (R<sub>SENSE</sub>). The internal resistor at RS- input (RG2) has the same value as RG1 to minimize the error. The current through RG1 is sourced by a high-voltage p-channel FET. Its source current is the same as the drain current which flows through a second gain resistor, R1, producing a voltage VR1 = V<sub>SENSE</sub> x R1/ RG1.

The output voltage V<sub>OUT</sub> is produced from a second op amp A2 with the gain (1 + RF1/ R1). Hence the V<sub>OUT</sub> =  $I_{LOAD} \times R_{SENSE}$  (R1/ RG1) x (1 + RF1/ R1). The value of internal resistors R1, R2, RG1, RG2, RF are available in <u>Table 1</u>.

Total gain is 12.5V/V for MAX40010L, 20V/V for the MAX40010T, 50V/V for the MAX40010F and 100V/V for the MAX40010H.

### **Application Information**

#### **Recommended Component Values**

Ideally, the maximum load current develops the full-scale sense voltage across the current-sense resistor. Choose the gain needed to yield the maximum output voltage required for the application:

#### $V_{OUT} = V_{SENSE} \times AV$

where  $V_{SENSE}$  is the full-scale sense voltage, 200mV for gain of 12.5V/V, 125mV for gain of 20V/V, 50mV for

gain of 50V/V, 25mV for gain of 100V/V, and AV is the gain of the device.

In applications monitoring a high current, ensure that  $R_{SENSE}$  is able to dissipate its own I<sup>2</sup>R loss. If the resistor's power dissipation exceeds the nominal value, its value may drift or it may fail altogether.

The MAX40010 sense a wide variety of currents with different sense-resistor values.

#### **Choosing the Sense Resistor**

Choose R<sub>SENSE</sub> based on the following criteria:

• Voltage Loss: A high  $\mathsf{R}_{SENSE}$  value causes the power-source voltage to degrade through IR loss. For minimal voltage loss, use the lowest  $\mathsf{R}_{SENSE}$  value.

• Accuracy: A high R<sub>SENSE</sub> value allows lower currents measured more accurately. This is due to offsets becoming less significant when the sense voltage is larger. For best performance, select R<sub>SENSE</sub> to provide approximately 200mV (gain of 12.5V/V), 125mV (gain of 20V/V), or 50mV (gain of 50V/V), 25mV (gain of 100V/V) of sense voltage for the full-scale current in each application.

|           | GAIN (V/V) | R1, R2 (kΩ) | RG1, RG2 (kΩ) | RF (kΩ) |
|-----------|------------|-------------|---------------|---------|
| MAX40010L | 12.5       | 25          | 10            | 100     |
| MAX40010T | 20         | 25          | 10            | 175     |
| MAX40010F | 50         | 25          | 10            | 475     |
| MAX40010H | 100        | 25          | 10            | 975     |

#### **Table 1. Internal Gain-Setting Resistors**

• Efficiency and Power Dissipation: At high current levels, the I<sup>2</sup>R losses in R<sub>SENSE</sub> can be significant. Consider this when choosing the resistor value and its power dissipation (wattage) rating. In addition, the sense resistor's value might drift if it heats up excessively.

• **Inductance**: Keep inductance low if I<sub>SENSE</sub> has a large high-frequency component. Wire-wound resistors have the highest inductance, while metal film is somewhat better. Low-inductance, metal-film resistors are also available. Instead of being spiral wrapped around a core, as in metal-film or wire wound resistors, they are a straight band of metal and are available in values under 1 $\Omega$ .

Take care to eliminate parasitic trace resistance from causing errors in the sense voltage because of the high currents that flow through R<sub>SENSE</sub>. Either use a four terminal current-sense resistor or use Kelvin (force and sense) PC board layout techniques.

#### **EMIRR Input Filter**

These devices have input EMI filters to prevent effects of radio frequency interference on the output. The EMI filters comprise passive devices that present significant higher impedance to RF signals. See the EMIRR vs. Frequency plot in the Typical Operating Characteristics section for details.

### **Typical Application Circuit**

An example of typical application (Figure 2) of this highvoltage, high-precision current-sense amplifier is in base station systems where there is a need to monitor the current flowing in the power amplifier. Such amplifier, depending on the technology, can be biased up to 50V or 60V thus requiring a current-sense amplifier like the MAX40010 with high voltage common mode. The very low input offset voltage of the MAX40010 minimizes the value of the external sense resistor, resulting in system power saving.



Figure 2: MAX40010 Used in Base Station Application

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### **Ordering Information**

| PART           | GAIN(V/V) | TEMP RANGE      | PIN-PACKAGE | TOP-MARK |
|----------------|-----------|-----------------|-------------|----------|
| MAX40010LAUT+* | 12.5      | -40°C to +125°C | 6 SOT23     | +ACUR    |
| MAX40010LAWT+* | 12.5      | -40°C to +125°C | 6 WLP       | +DX      |
| MAX40010TAUT+* | 20        | -40°C to +125°C | 6 SOT23     | +ACUS    |
| MAX40010TAWT+* | 20        | -40°C to +125°C | 6 WLP       | +DY      |
| MAX40010FAUT+  | 50        | -40°C to +125°C | 6 SOT23     | +ACUT    |
| MAX40010FAWT+* | 50        | -40°C to +125°C | 6 WLP       | +DV      |
| MAX40010HAUT+* | 100       | -40°C to +125°C | 6 SOT23     | +ACUU    |
| MAX40010HAWT+* | 100       | -40°C to +125°C | 6 WLP       | +DW      |

\*Future Product—Contact factory for availability.

+Denotes a lead(Pb)-free/RoHS-compliant package.

### **Package Information**

For the latest package outline information and land patterns (footprints), go to <u>www.maximintegrated.com/packages</u>. Note that a "+", "#", or "-" in the package code indicates RoHS status only. Package drawings may show a different suffix character, but the drawing pertains to the package regardless of RoHS status.

| PACKAGE TYPE | PACKAGE CODE | OUTLINE NO.      | LAND PATTERN NO.               |
|--------------|--------------|------------------|--------------------------------|
| 6 WLP        | W61K1+1      | <u>21-100121</u> | Refer to Application Note 1891 |
| 6 SOT23      | U6SN+1       | 21-0058          | <u>91-0175</u>                 |

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### **Revision History**

| REVISION | REVISION | DESCRIPTION     | PAGES   |
|----------|----------|-----------------|---------|
| NUMBER   | DATE     |                 | CHANGED |
| 0        | 10/16    | Initial release | —       |

For pricing, delivery, and ordering information, please contact Maxim Direct at 1-888-629-4642, or visit Maxim Integrated's website at www.maximintegrated.com.

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